



20V P-CHANNEL ENHANCEMENT MODE MOSFET POWERDI®

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	$8m\Omega @ V_{GS} = -4.5V$	-14A
-20V	$9.8 m\Omega @ V_{GS} = -2.5 V$	-10A
	$13m\Omega$ @ $V_{GS} = -1.8V$	-9.3A
	$17m\Omega$ @ $V_{GS} = -1.5V$	-8.3A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

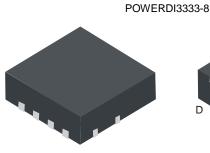
- Load Switch
- Power Management Functions

Features

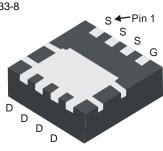
- Low R_{DS(ON)} ensures on state losses are minimized
- Small form factor thermally efficient package enables higher density end products
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 standards for High Reliability

Mechanical Data

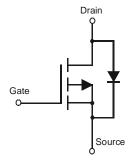
- Case: POWERDI3333-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See diagram
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (approximate)







Bottom View



Internal Schematic

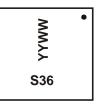
Ordering Information (Note 4)

f -		
Part Number	Case	Packaging
DMP2008UFG-7	POWERDI3333-8	2000/Tape & Reel
DMP2008UFG-13	POWERDI3333-8	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



S36 = Product Type Marking Code YYWW = Date Code Marking YY = Last digit of year (ex: 11 = 2011) WW = Week code (01 ~ 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units		
Drain-Source Voltage	V_{DSS}	-20	V		
Gate-Source Voltage (Note 5)	V_{GSS}	±8	V		
Continuous Drain Current (Note 6) V _{GS} = -4.5V	I _D	-14 -11 -54	А		
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-80	Α		
Maximum Continuous Body Diode Forward Current (Note 6)			Is	-2.2	Α
Avalanche Current (Note 8)			I _{AS}	-15	Α
Avalanche Energy (Note 8)			E _{AS}	-113	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units	
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$,	2.4	- W
Total Power Dissipation (Note 6)	$T_C = +25$ °C	P _D	41	
Thermal Resistance, Junction to Ambient	(Note 5)	Po	52	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	137	
Thermal Resistance, Junction to Case (Note 6)	Rejc	3.0		
Operating and Storage Temperature Range	$T_{J_i}T_{STG}$	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	I	-1	μA	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_		±100	nA	$V_{GS} = \pm 8V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(th)}	-0.4		-1.0	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
		_		8	mΩ	$V_{GS} = -4.5V$, $I_{D} = -12A$	
Static Drain-Source On-Resistance	D	_	1	9.8		$V_{GS} = -2.5V$, $I_{D} = -10A$	
Static Diani-Source Off-Resistance	R _{DS (ON)}	_	l	13	11152	$V_{GS} = -1.8V$, $I_{D} = -9.3A$	
		_		17		$V_{GS} = -1.5V, I_D = -8.3A$	
Forward Transfer Admittance	Y _{fs}	_	42	_	S	$V_{DS} = -5V, I_{D} = -12A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	_	6909	_		V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss	_	635	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	563	_			
Gate Resistance	R _G	_	2.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Q_g	_	72	_			
Total Gate Charge (V _{GS} = -2.5V)	Q_g	_	40	_	nC	\/ 10\/ I- 12A	
Gate-Source Charge	Q_{gs}	_	8.6	_	IIC	$V_{DD} = -10V, I_D = -12A$	
Gate-Drain Charge	Q_{gd}	_	14.5	_			
Turn-On Delay Time	t _{D(on)}	_	22	_			
Turn-On Rise Time	t _r	_	33	_		$V_{GS} = -4.5V$, $V_{DD} = -10V$, $R_G = 6\Omega$, $I_D = -12A$	
Turn-Off Delay Time	t _{D(off)}	_	291	_	ns		
Turn-Off Fall Time	t _f	_	124	_			
BODY DIODE CHARACTERISTICS							
Diode Forward Voltage	V_{SD}	_	-0.7	_	V	$V_{GS} = 0V, I_{S} = -12A$	
Diode i diwalu voltage	v SD	_	-0.7	_	V	$V_{GS} = 0V$, $I_S = -2A$	
Reverse Recovery Time (Note 10)	t _{rr}	_	25	_	ns	$I_F = -12A$, $di/dt = 100A/\mu s$	
Reverse Recovery Charge (Note 10)	Q _{rr}		15	_	nC	I _F = -12A, di/dt = 100A/μs	

Notes: 5. AEC-Q101 V_{GS} maximum is $\pm 6.4 V$.

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^{6.} R_{BJA} is determined with the device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. R_{BJC} is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design.

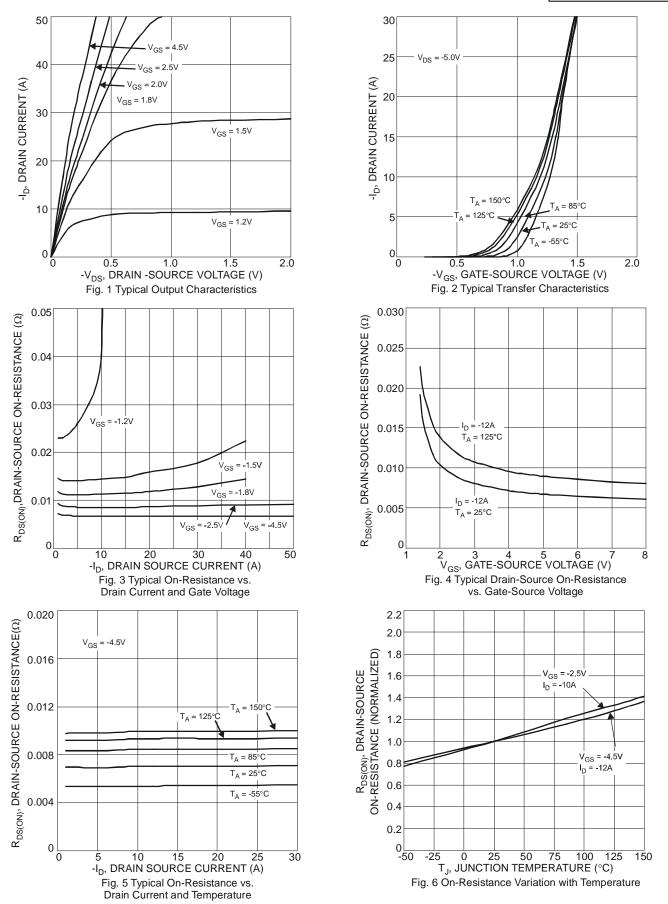
^{7.} Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. 8 .UIS in production with L = 1mH, T_J = +25°C.

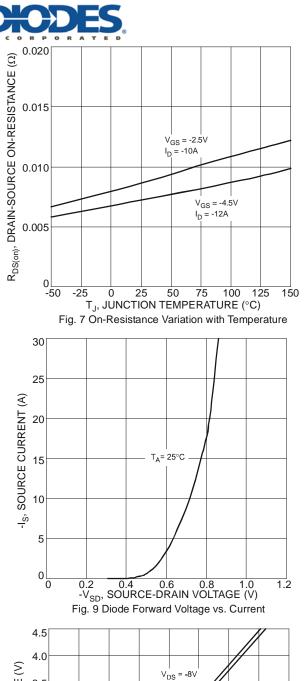
^{9.} Short duration pulse test used to minimize self-heating effect.

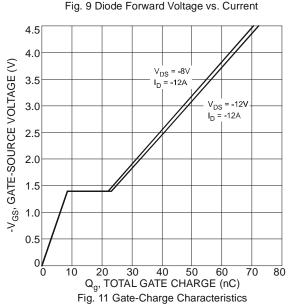
^{10.} Guaranteed by design. Not subject to product testing.











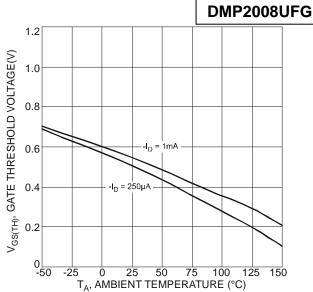
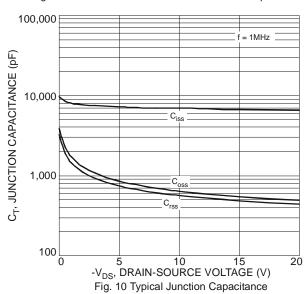


Fig. 8 Gate Threshold Variation vs. Ambient Temperature



100

R_{DS(01)}

Limited

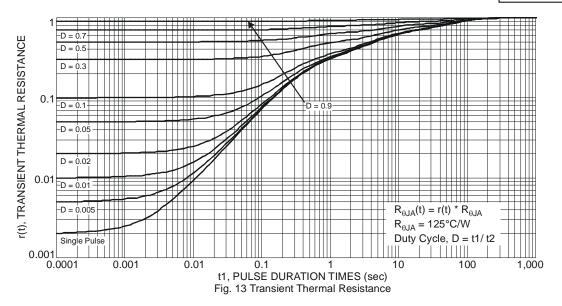
10

P_W = 10s

P_W = 10ms

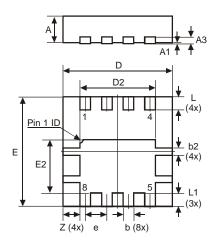
P_W





Package Outline Dimensions

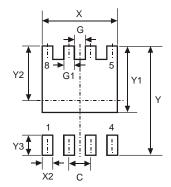
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



POWERDI3333-8					
Dim	Min	Max	Тур		
ם	3.25	3.35	3.30		
Е	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E2	1.56	1.66	1.61		
Α	0.75	0.85	0.80		
A1	0	0.05	0.02		
A3	-	-	0.203		
b	0.27	0.37	0.32		
b2	_	_	0.20		
L	0.35	0.45	0.40		
L1	_	_	0.39		
е	_	_	0.65		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
С	0.650			
G	0.230			
G1	0.420			
Y	3.700			
Y1	2.250			
Y2	1.850			
Y3	0.700			
X	2.370			
X2	0.420			



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